Formation of Nanostructured Films of Polycrystalline Silicon Doped with Germanium A. A. Kovalevskii 1, A. S. Strogova 2, O. M. Komar 3

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Abstract: The impact of germanium as isovalent impurity on the process of formation of nanostructured films of polycrystalline silicon doped with germanium is investigated.
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